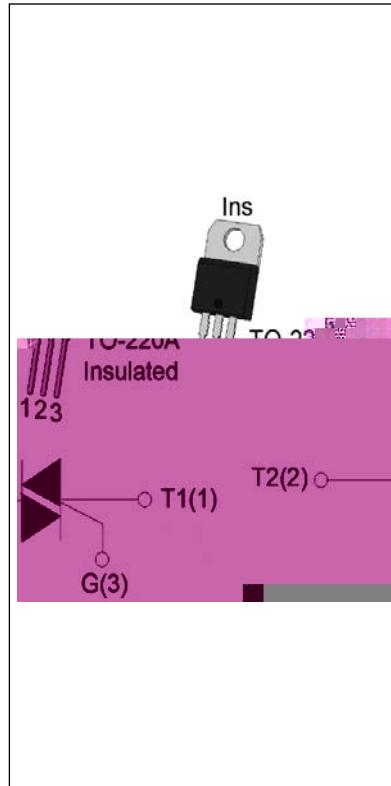


The JST24A-600CW triac is suitable for general purpose AC switching. It can be used as an ON/OFF function in applications such as heating regulation, induction motor starting circuits, for phase control operation in light dimmers, motor speed controllers. JST24A-600CW snubberless triac is especially recommended for use on inductive loads. By using an internal ceramic pad, JST24A-600CW provides a rated insulation voltage of 2500 VRMS, complying with UL standards (File ref: E252906). Package TO-220A is RoHS compliant.



Symbol	Value	Unit
$I_{T(RMS)}$	25	A
V_{DRM}/V_{RRM}	600	V
$I_{GT\text{ I/II/III}}$	35/35/35	mA

Storage junction temperature range	T_{stg}	-40-150	°C
Operating junction temperature range	T_j	-40-125	°C
Repetitive peak off-state voltage ($T_j=25^\circ\text{C}$)	V_{DRM}	600	V
Repetitive peak reverse voltage ($T_j=25^\circ\text{C}$)	V_{RRM}	600	V
RMS on-state current ($T_c \leq 79^\circ\text{C}$)	$I_{T(RMS)}$	25	A
Non repetitive surge peak on-state current (full cycle , $t_p=20\text{ms}$, $T_j=25^\circ\text{C}$)	I_{TSM}	250	A
Non repetitive surge peak on-state current (full cycle , $t_p=16.6\text{ms}$, $T_j=25^\circ\text{C}$)		275	
I^2t value for fusing ($t_p=10\text{ms}$, $T_j=25^\circ\text{C}$)	I^2t	340	A^2s
Critical rate of rise of on-state current ($I_G=2 \times I_{GT}$, $f=100\text{Hz}$, $T_j=125^\circ\text{C}$)	dI/dt	100	$\text{A}/\mu\text{s}$
Peak gate current ($t_p=20\mu\text{s}$, $T_j=125^\circ\text{C}$)	I_{GM}	4	A
Average gate power dissipation ($T_j=125^\circ\text{C}$)	$P_{G(AV)}$	0.5	W



Peak gate power	P_{GM}	10	W
Peak pulse voltage ($T_j=25^\circ C$; non-repetitive, off-state; FIG.7)	V_{pp}	2.5	kV

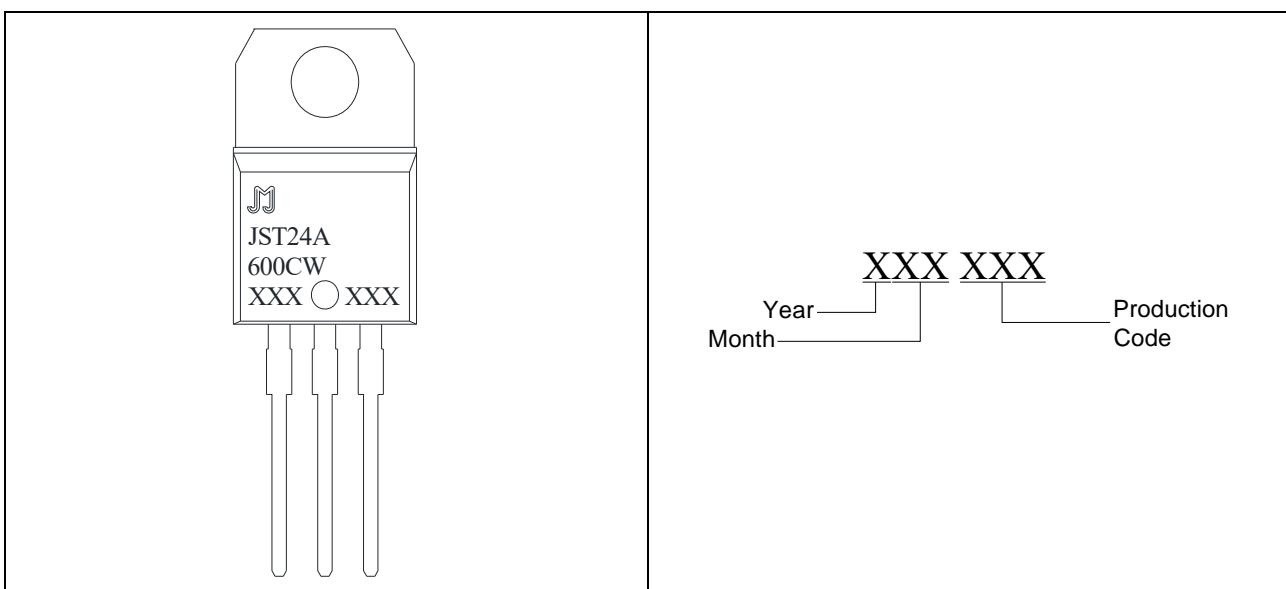
($T_j=25^\circ C$ unless otherwise specified)

I_{GT}	$V_D=12V$ $R_L=33$	I - II - III	MAX.	35	mA
V_{GT}		I - II - III	MAX.	1	V
V_{GD}	$V_D=V_{DRM}$ $T_j=125^\circ C$ $R_L=3.3K$	I - II - III	MIN.	0.2	V
I_L	$I_G=1.2I_{GT}$	I - III	MAX.	70	mA
		II		80	
I_H	$I_T=500mA$		MAX.	50	mA
dV/dt	$V_D=400V$ Gate Open $T_j=125^\circ C$		MIN.	1500	V/ μs
$(dI/dt)c$	$(dV/dt)c=20V/\mu s$ $T_j=125^\circ C$		MIN.	15	A/ms
t_{on}	$I_G=40mA$ $I_A=200mA$ $I_R=20mA$ $T_j=25^\circ C$	TYP.	7	μs	
t_{off}			50		

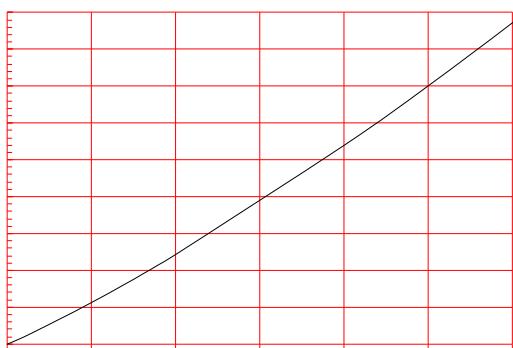
V_{TM}	$I_{TM}=35A$ $t_p=380\mu s$	$T_j=25^\circ C$	1.5	V
V_{TO}	Threshold voltage	$T_j=125^\circ C$	0.75	V
R_D	Dynamic resistance	$T_j=125^\circ C$	18	m
I_{DRM}	$V_D=V_{DRM}$ $V_R=V_{RRM}$	$T_j=25^\circ C$	5	μA
I_{RRM}		$T_j=125^\circ C$	1.5	mA



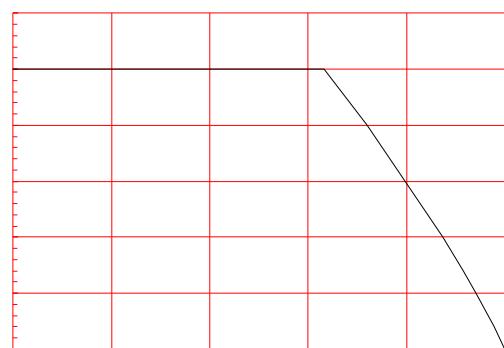
J	ST	24	A	-600	CW
JieJie Microelectronics Co., Ltd.					
	Triacs				
		<u>$I_{T(RMS)}:25A$</u>			
			A:TO-220A(Ins)		
					<u>$CW:IGT1-3 \leq 35mA$</u>
				600: $V_{DRM} / V_{RRM} \geq 600V$	



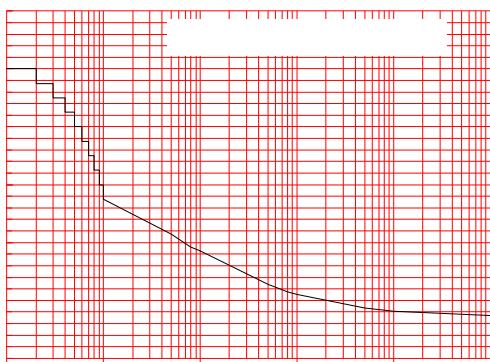
Maximum power dissipation versus RMS on-state current



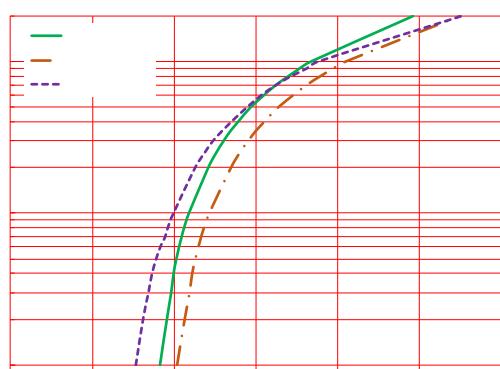
RMS on-state current versus case temperature



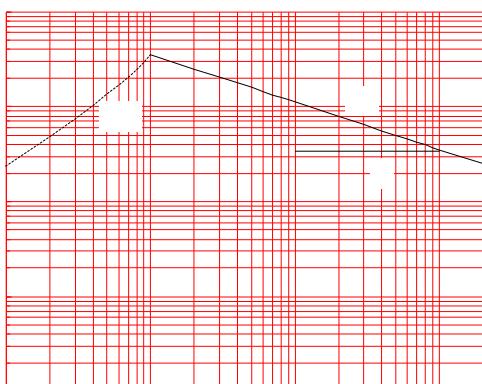
Surge peak on-state current versus number of cycles



On-state characteristics



Non-repetitive surge peak on-state current for a sinusoidal pulse with width $t_p < 20\text{ms}$, and corresponding value of I^2t ($dI/dt < 100\text{A}/\mu\text{s}$)



Relative variations of gate trigger current, holding current and latching current versus junction temperature

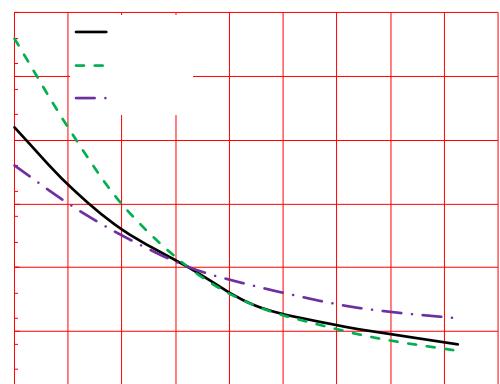
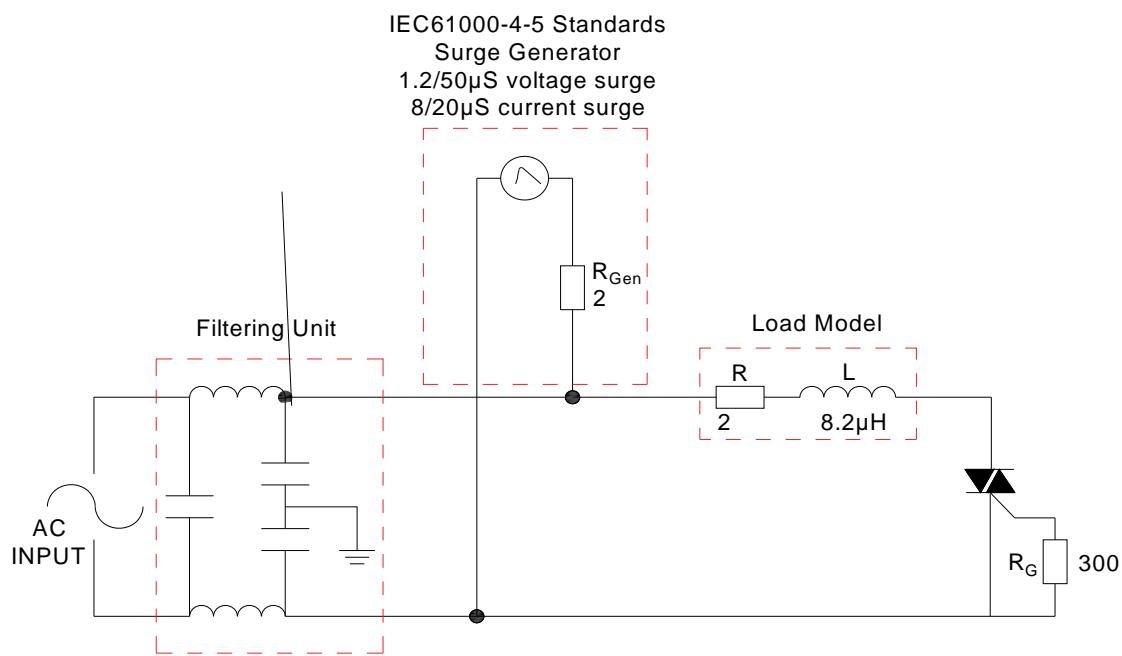
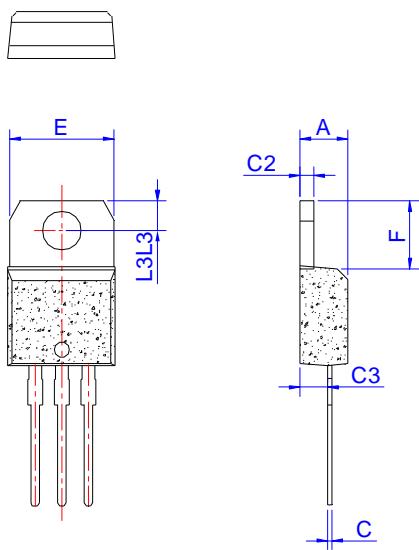


FIG.7: Test circuit for inductive and resistive loads to IEC-61000-4-5 standards





Date	Revision	Changes
Apr.12, 2023	A.1.0	Last updated





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